NSN 5961-00-006-1350

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Inclosure Material:	
Metal	
Overall Length:	
0.085 inches	
Overall Diameter:	
0.230 inches	
Internal Configuration:	
Junction contact	
Electrode Internally-ele	ctrically Connected To Case:
Collector	
Internal Junction Config	guration:
Npn	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Materia	1:
Silicon	
Voltage Rating In Volts	Per Characteristic:
60.0 breakdown voltage,	, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdow
voltage, emitter-to-base,	collector open
Current Rating Per Cha	racteristic:
20.00 milliamperes colle	ctor current, dc
Power Rating Per Chara	acteristic:
50.0 watts small-signal in	nput power, common-collector
Maximum Operating Te	mpurature Per Measurement Point:
200.0 degrees celsius jur	nction
Terminal Type And Qua	antity:
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	